Possible nodal superconducting gap and Lifshitz transition in heavily hole-doped Ba_{0.1}K_{0.9}Fe₂As₂

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We performed a high-energy resolution angle-resolved photoemission spectroscopy investigation of overdoped $Ba_{0.1}K_{0.9}Fe_2As_2$ with $T_c = 9$ K. The Fermi surface topology of this material is similar to that of KFe₂As₂ and differs from that of slightly less doped $Ba_{0.3}K_{0.7}Fe_2As_2$, implying that a Lifshitz transition occurred between x = 0.7 and x = 0.9. Albeit for a vertical node found at the tip of the emerging off-*M*-centered Fermi surface pocket lobes, the superconducting gap structure is similar to that of $Ba_{0.3}K_{0.7}Fe_2As_2$, suggesting that the pairing interaction is not driven by the Fermi surface topology, but nevertheless reveals the possible importance of the Fermi surface topology in shaping the superconducting gap structure.

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The discovery of high-temperature superconductivity without a hole Fermi surface (FS) pocket¹⁻⁷ in AFe_2Se_2 (A = TI, K, Cs, and Rb) imposed severe constraints to the electron-hole quasinesting scenario as the main Cooper pairing force in the Fe-based superconducting (SC) materials⁸ and raised fundamental questions related to the importance of their FS topology. To answer these questions, it is necessary to investigate heavily hole-doped compounds. Previous angleresolved photoemission spectroscopy (ARPES) studies of fully hole-doped KFe₂As₂ indicate that the FS near the $M(\pi,0)$ point is formed by small off-M-centered hole FS pocket lobes^{9,10} rather than the *M*-centered ellipsoidlike electron FS pockets commonly observed in the other materials.⁸ Interestingly, KFe₂As₂ has a very low critical temperature (T_c) of only 3 K,^{11,12} which was earlier⁹ interpreted as, and is still widely considered as, a consequence of the evolution of the FS topology. The functional renormalization group study¹³ predicts a *d*-wave superconducting state in the heavily overdoped region of $Ba_{1-x}K_xFe_2As_2$. However, despite their incapability to access the band structure at the M point and thus to reveal completely the SC gap structure, laser-ARPES measurements suggest a rather complicated nodal SC gap profile around the Γ point,¹⁴ which is consistent with the finite residual thermal conductivity (κ_0/T) of this material at low temperature.^{15,16}

While their existence is widely accepted, the origin of the nodes in KFe₂As₂ and their relationship with the pairing mechanism remain unclear and could possibly involve a fundamental change in the SC order parameter upon doping K from the optimal Ba_{0.6}K_{0.4}Fe₂As₂ composition, for which both the ARPES^{17–19} and thermal conductivity²⁰ techniques agree on a nodeless SC gap. Indeed, Tafti *et al.*²¹ recently reported a sudden reversal in the pressure (*P*) dependence of *T_c* in KFe₂As₂ without discontinuity in the Hall coefficient *R_H(P)* and in the electrical resistivity $\rho(P)$, which was interpreted as an evidence for a change in the order parameter incompatible with a Lifshitz transition (change in the FS topology²²).

Based on a rigid-band shift model, the Lifshitz transition corresponding to the appearance of the small off-*M*-centered hole FS pocket lobes was estimated to occur within the $0.8 \le x \le 0.9$ doping range.²³ Determining the *k*-space structure of the SC gap in the vicinity of this transition is of critical importance.

In this Rapid Communication, we investigate the electronic structure and SC gap of heavily hole-doped Ba_{0.1}K_{0.9}Fe₂As₂ in the vicinity of the Lifshitz transition associated with the FS topology around the *M* point. While the FS topology at the Γ point remains unchanged as compared with that of Ba_{0.3}K_{0.7}Fe₂As₂,²³ four small off-*M*-centered hole FS pocket lobes emerge in Ba_{0.1}K_{0.9}Fe₂As₂. We observe rather isotropic SC gaps at T = 0.9 K, albeit for nodes found at the tips of the new emerging ε FS lobes. Despite such strong modification of the FS topology, the T_c of this material remains as high as 9 K around this particular doping for which no big jump of T_c has been reported.^{11,12} Our results indicate that the FS topology is unlikely the main driving force for the pairing mechanism in these compounds, but that it is not completely independent of the gap structure.

Large single crystals of Ba_{0.1}K_{0.9}Fe₂As₂ were grown by the self-flux method.²⁴ ARPES measurements were performed at Swiss Light Source surface/interface spectroscopy beamline and at the one-cubed ARPES end station of BESSY using VG-Scienta R4000 electron analyzers with photon energy ranging from 20 to 80 eV. The angular resolution was set to 0.2° and the energy resolution to 2–10 meV for SC gap and band structure measurements, respectively. Clean surfaces for the ARPES measurements were obtained by cleaving crystals *in situ* in a working vacuum better than 5×10^{-11} Torr. We label the momentum (*k*) values with respect to the 1 Fe/unit cell Brillouin zone (BZ), and use c' = c/2 as the distance between two Fe planes.

We show in Figs. 1(a) and 1(b) the ARPES FS intensity mappings recorded with hv = 43 eV and hv = 60 eV, respectively. As determined from our hv analysis, these



FIG. 1. (Color online) (a) ARPES FS intensity mapping ($\pm 5 \text{ meV}$ integration) recorded with hv = 43 eV ($k_z = 0$). (b) Same as (a) but with hv = 60 eV ($k_z = \pi$). Symbols indicate the k_F positions and the labeled red lines in (b) indicate ARPES cuts shown in (e)–(h). (c) ARPES FS intensity mapping in the k_x - k_z plane. (d) ARPES intensity cut along Γ -Z. (e)–(g) ARPES intensity plot recorded with hv = 31 eV ($k_z = \pi$) along the ε pockets [cuts 1–3 in (b)]. The red curves are the MDCs at E_F . (h) ARPES intensity plot recorded with hv = 31 eV ($k_z = \pi$) along the Z-A direction, in the vicinity of the A point [cut 4 in (b)]. (i) Corresponding EDCs.

 $h\nu$ values correspond respectively to out-of-plane momentum (k_z) values equivalent to 0 and π . Similarly to optimally doped Ba_{0.6}K_{0.4}Fe₂As₂ (Refs.17 and 18) and overdoped $Ba_{0.3}K_{0.7}Fe_2As_2$,²³ three hole FS pockets are distinguished at the BZ center (Γ), two of them being nearly degenerate at $k_z = 0$. Instead of *M*-centered ellipsoid electron FS pockets, the intensity mappings exhibit off-*M*-centered lobes slightly elongated along the Γ -M axis, which correspond to the ε FS pockets in Ref. 9. Below we show that in contrast to overdoped $Ba_{0.3}K_{0.7}Fe_2As_2$,²³ and similarly to KFe_2As_2 ,^{9,10} this intensity comes from a band crossing the Fermi level (E_F) rather than a band topping slightly below E_F . We caution that some weak intensity is also found at the M point. Supported by our band structure calculations illustrated in Fig. 4, we attribute this intensity to the tail of the electron bands pushed above E_F following hole doping. However, we cannot completely rule out the possibility that one electron band is still crossing E_F and forming a tiny electron FS pocket at M.

The dispersion obtained by converting hv into k_z using the nearly-free electron approximation²⁵ with an inner potential of 12.5 eV is displayed in Fig. 1(c). It shows small k_z warping of the FS, especially for the quasidegenerate inner hole bands centered at Γ . This k_z warping is small for the ε band, confirming that the FS topology does not depend on the probing hv value. Using the full set of ARPES data and the Luttinger theorem, we estimate the hole concentration to be $x \sim 0.84$, which is close to the nominal composition. Interestingly, the $k_x - k_z$ mapping displayed in Fig. 1(c) shows

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some additional ARPES intensity at the $Z(0,0,\pi)$ point. This feature originates from a highly k_z -dispersive hole band, most likely of d_{z^2} orbital character, whose top oscillates from -40 to -220 meV, as illustrated in Fig. 1(d).

We present a more detailed analysis of the ε pockets in Figs. 1(e)–(g), using ARPES cuts perpendicular to the *Z*-*A* direction for the $k_z \sim \pi$ [cuts 1–3 from Fig. 1(b)]. While the band is not crossing E_F along cut 1, as confirmed by the momentum distribution curve (MDC) at E_F , we identify k_F vectors separated by $0.05\pi/a$ along cut 2, indicating that the top of the ε band has emerged. The spacing becomes slightly smaller, $0.04\pi/a$, along cut 3. The ARPES intensity cut along *Z*-*A* for $k_z \sim \pi$ [cut 4 from Fig. 1(b)] is shown in Fig. 1(h), and the corresponding energy dispersive curves (EDCs) are shown in Fig. 1(i). Clearly, the β band turns up around $k_y = \pm 0.50\pi/a$ and crosses E_F to form the small hole ε FS with the γ band, as in KFe₂As₂.^{9,10} As mentioned above, also observe some intensity at the *A* point attributed to the band bottom of the electronlike δ band slightly above E_F .

As predicted from our previous data,²³ our Ba_{0.1}K_{0.9}Fe₂As₂ results clearly show that a Lifshitz transition occurs between x = 0.7 and x = 0.9 upon hole doping the Ba_{1-x}K_xFe₂As₂ system. In order to investigate the interplay between the FS topology and the SC gap structure, we conducted high-energy resolution ARPES measurements at T = 0.9 K, way below the SC transition. In Fig. 2, we plot the SC gap results for FSs located at the BZ center (Γ/Z). The summaries of



FIG. 2. (Color online) (a) Schematic FS around the BZ center and definition of the polar angle θ . The axes coincide with the Γ -*M* directions. (b) SC gap size as a function of θ at 0.9 K for the nearly degenerate α/α' FSs and the β FS, at $k_z \sim 0$. (c) Same as (b), but for the α and α' FSs at $k_z \sim \pi$. (d) Symmetrized EDCs for different polar angles of the α/α' bands at $k_z \sim 0$. (e) Same as (d), but for the β band. (f), (g) Symmetrized EDCs for different polar angles of the α and α' bands at $k_z \sim \pi$, respectively. (f), (g) EDC plots at $k_z \sim \pi$ for the α , α' , and β bands, respectively. (h), (i) Symmetrized EDCs at different $h\nu$ values for the α and β bands, respectively.

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the SC gap amplitudes as a function of the polar angle θ defined in Fig. 2(a) are shown in Figs. 2(b) and 2(c) at $k_z \sim 0$ and $k_z \sim \pi$, respectively. The corresponding symmetrized EDCs are displayed in Figs. 2(d)–2(g). Within experimental uncertainties, a constant SC gap of $\Delta_{\alpha/\alpha'}^{k_z=0} = 3.6$ meV is extracted along the α/α' FSs at $k_z \sim 0$. A slightly smaller but still isotropic gap of $\Delta_{\beta}^{k_z=0} = 2.7$ meV is extracted for the β band. At $k_z \sim \pi$, where the α and α' bands can be resolved, our results indicate isotropic SC gaps with almost identical sizes of $\Delta_{\alpha}^{k_z=\pi} = 2.7$ meV and $\Delta_{\alpha'}^{k_z=\pi} = 2.5$ meV, respectively. Unfortunately, the weakness of the coherence peak associated with the β band near $k_z = \pi$ does not allow a reliable determination of the SC gap. Nevertheless, our $h\nu$ dependent measurements along Γ -M suggest that the SC gap size on all the Γ -centered hole FSs does not vary too much along k_z .

Now we focus on the SC gap of the ε pockets, for which the *k* location of the measured cuts and points are shown in Fig. 3(a). In Figs. 3(b)–3(e), we display the symmetrized ARPES intensity at T = 0.9 K for various cuts at $k_z \sim \pi$, and the symmetrized EDCs along the ε FS at several k_F positions indicated in Fig. 3(a) are plotted in Figs. 3(f) and 3(i) at $k_z \sim 0$ and $k_z \sim \pi$, respectively. Interestingly, a SC gap opens along the ε pockets, except at points labeled 1, 8, and 10, which correspond to the tip position of the ε lobes. As shown in Figs. 3(g) and 3(h) and Figs. 3(j) and 3(k) for $k_z \sim 0$ and $k_z \sim \pi$, respectively, these SC nodes are confirmed by the absence of a leading edge gap in the related EDCs as compared to the other locations.



FIG. 3. (Color online) (a) Momentum location of ARPES cuts (labeled red lines) shown in (b)–(e). The symbols indicate k_F positions of the EDCs and symmetrized EDCs in (f)–(k). (b)–(e) Symmetrized ARPES intensity plots for the C1, C2, C3, and C4 cuts. The labeled yellow lines are k_F positions of the EDCs and symmetrized EDCs in (f)–(k). (f) Symmetrized EDCs along the ε FS at $k_z = 0$. (g), (h) EDCs along the ε FS at $k_z = 0$. (i)–(k) Same as (f)–(h) but for $k_z = \pi$.

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FIG. 4. (Color online) (a), (b) Schematic FS of $Ba_{1-x}K_xFe_2As_2$ for x = 0.7 and 0.9, respectively. (c) SC gap size at 0.9 K along the ε FS as a function of the angle φ (defined in the inset). The pink line is a guide for the eye. (d) FS of $Ba_{0.1}K_{0.9}Fe_2As_2$ with the ε FS pockets shifted by $(-\pi, 0)$. The color scale represents the amplitude of the cos $k_x \cos k_y$ global pairing function. (e) LDA band structure calculations from Ref. 26, renormalized by a factor 2. The location of the chemical potential is indicated for several doping levels. (f) Location of the Lifshitz transition in $Ba_{1-x}K_xFe_2As_2$ with respect to the phase diagram extracted from Ref. 11.

The angular distribution of the SC gap along the ε FS is shown in Fig. 4(c). To check the origin of the SC gap anomaly at the tip position ($\varphi = 0$), we display in Fig. 4(d) the FS of this material at $k_z \sim \pi$ after shifting the ε FS lobes by $(-\pi, 0)$. For convenience, we added a color scale proportional to the amplitude of the $|\cos(k_x)\cos(k_y)|$ global pairing function expected from the strong-coupling approach and the effective J_1 - J_2 model.^{27–31} While the absence of nodes around the Γ point is inconsistent with a *d*-wave gap symmetry and matches well the global gap function, our finding of nodes on the ε FS cannot be explained by this simple gap function since the ε FS pockets locate far from the nodal lines. Interestingly, the superimposition of the ε FS with the Γ -centered FSs at $k_z \sim \pi$ may offer possible hints to explain the origin of the nodes. Indeed, while the flatter part of the ε FS near $\varphi = 90^{\circ}$ is connected to the α FS by the $(\pi, 0)$ wave vector, the tip of the ellipsoid is linked to the α' FS by the same wave vector. Although the details of the low-energy scattering would depend on the orbital components at each FS point, similar effect has been invoked to explain the departure from the $|\cos(k_x)\cos(k_y)|$ gap function in LiFeAs.³² We caution though that the situation is different at $k_z \sim 0$, where the α and α' FSs are nearly degenerate, and that further theoretical work would be necessary to validate this scenario.

A Lifshitz transition has been evidenced at low electron doping in the Ba(Fe_{1-x}Co_x)₂As₂ system. Due to long-range antiferromagnetic ordering, the non-SC parent compound BaFe₂As₂ undergoes a nontrivial reconstruction of its electronic band structure characterized by Dirac cones.^{33–35} Upon electron doping, a previous study indicates that the emergence of superconductivity occurs when this band structure reconstruction disappears.³⁶ Our results prove that a Lifshitz transition also takes place upon hole doping the $Ba_{1-x}K_xFe_2As_2$ system from x = 0.7 to x = 0.9, which is shown in Figs. 4(a) and 4(b). Within the framework of the electron-hole quasinesting scenario,^{8,37,38} the replacement of the *M*-centered electron FS pockets by the hole ε FS pockets should be harmful to superconductivity. Unless the electron FS pockets do not play any important role in the Cooper pairing, we argue that the Lifshitz transition should also have a large impact on the SC properties determined from other weak-coupling scenarios, for example by significantly changing the intrapocket and inter-scattering involved in some models.³⁹ In contrast, pairing described by strong-coupling approaches^{27–31} should suffer smaller influence, although for a given pairing interaction different Fermi- surface topologies can lead to different pairing symmetries.²⁹

To put our findings in context, we digitized the early phase diagram of the $Ba_{1-x}K_xFe_2As_2$ system reported by Rotter et $al.^{11}$ in Fig. 4(f). Albeit for a small slope change around x = 0.8, the critical temperature $T_c(x)$ evolves smoothly on the overdoped side of the phase diagram. According to our local density approximation (LDA) calculations reproduced in Fig. 4(e), this slope change seems correlated to the Lifshitz transition associated with the emergence of the ε pockets. While the FS topology is changed, T_c remains relatively high, which contrasts with intuitive description of the SC properties from a weak-coupling scenario and suggests that the driving SC force is the same throughout the whole phase diagram. Moreover, it suggests that the Lifshitz transition observed here has a fundamentally different nature from the one observed in $Ba(Fe_{1-x}Co_x)_2As_2$,³⁶ where long-range antiferromagnetism is suppressed.

Our findings also allow us to interpret the recent discovery of a sign reversal in the P dependence of T_c in KFe₂As₂

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with perspectives different from that of Tafti et al.²¹ In their analysis, Tafti et al. adopt a weak-coupling approach and neglect the existence of the ε FS lobes, thus neglecting the possibility of having nodes on that particular FS. Assuming that this node is induced by low-energy interband scattering, it is plausible that the FS evolves only slightly, without any Lifshitz transition or large size variation of the FS pockets, so that the interband scattering between the tip of the ε lobes and the α' band is suppressed, leading to a sign reversal in the P dependence of T_c without jump in $R_H(P)$ or $\rho(P)$. Alternatively, the value of T_c within the strong-coupling approach is controlled by local J parameters, which are themselves dependent on the Fe-As bounding. In this context, it is natural to encounter extrema in the Fe-As bounding configuration as a function of P, thus explaining the sign reversal in the P dependence of T_c without invoking modification of the FS topology or even a change in the symmetry of the order parameter. Yet, further studies are necessary to confirm or infirm the original interpretation of Tafti et al.

In summary, we showed that the FS topology of overdoped $Ba_{0.1}K_{0.9}Fe_2As_2$ with $T_c = 9$ K is similar to that of KFe_2As_2. Since T_c does not change significantly across the corresponding Lifshitz transition, we infer from our results that the pairing mechanism is unlikely driven by the FS topology, at least around the M point, but that the FS topology correlates with the precise shape of the superconducting gap symmetry. We observe a SC gap opening at T = 0.9 K, with nodes at the tips of the emerging ε pockets. Our result suggests that the SC gap symmetry is still S_{\pm} , instead of d wave, and is more consistent with a strong-coupling approach.

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